

PATENT
81788.0026

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

MORI, Seiichi

Serial No: 09/456,873

Filed: December 8, 1999

For: NON-VOLATILE
SEMICONDUCTOR MEMORY
DEVICE

Art Unit: 2826

Examiner: ANDÚJAR, L.

#17/0
9/25/02
gem

I hereby certify that this correspondence is being
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Trademark Office, Art Unit 2826, at (703) 308-7722,
on

September 23, 2002

Date of Transmission

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Name

Michael L. Crapenchoff

September 23, 2002

Signature

Date

AMENDMENT

Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the Office Action dated May 22, 2002, the due date for
response to which is extended by one month to September 23, 2002 (September 22
being a Sunday) in the accompanying Petition for Extension of Time, please amend
the above-referenced application as follows:

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IN THE SPECIFICATION:

TECHNOLOGY CENTER 2800

- o Please replace the paragraph at page 1, lines 19-25, with the following
amended text:

FIGS. 4A and 4B show sections, taken in two directions
orthogonal to each other, of the memory cell structure described above.
Normally in a flash memory, the control gates of a plurality of memory
cells are consecutively arranged and serve as word lines. FIG. 4A is
the section in the direction parallel to a direction of the word line.